2N2907A

Small Signal Switching Transistor

PNP Silicon

Features

- MIL-PRF-19500/291 Qualified
- Available as JAN, JANTX, and JANTXV

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|-----------------------------------|-------------|------|
| Collector - Emitter Voltage | V _{CEO} | -60 | Vdc |
| Collector - Base Voltage | V _{CBO} | -60 | Vdc |
| Emitter - Base Voltage | V _{EBO} | -5.0 | Vdc |
| Collector Current - Continuous | I _C | -600 | mAdc |
| Total Device Dissipation @ T _A = 25°C | P _T | 500 | mW |
| Total Device Dissipation @ T _C = 25°C | P _T | 1.0 | W |
| Operating and Storage Junction Temperature Range | T _J , T _{stg} | -65 to +200 | °C |

THERMAL CHARACTERISTICS

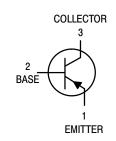
| Characteristic | Symbol | Max | Unit |
|---|-----------------|-----|------|
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 325 | °C/W |
| Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 150 | °C/W |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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TO-18 CASE 206AA STYLE 1

ORDERING INFORMATION

| Device | Package | Shipping |
|---------------|---------|----------|
| JAN2N2907A | | |
| JANTX2N2907A | TO-18 | Bulk |
| JANTXV2N2907A | | |

2N2907A

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

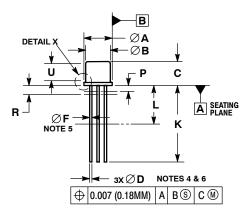
| Characteristic | Symbol | Min | Max | Unit |
|--|----------------------|-------------------------------|---------------------------|--------------|
| OFF CHARACTERISTICS | • | | | |
| Collector – Emitter Breakdown Voltage (I _C = -10 mAdc) | V _{(BR)CEO} | -60 | _ | Vdc |
| Collector – Emitter Cutoff Current (V _{CE} = -50 Vdc) | Ices | _ | -50 | nAdc |
| Collector–Base Cutoff Current $(V_{CB} = -50 \text{ Vdc}, I_E = 0)$ $(V_{CB} = -60 \text{ Vdc}, I_E = 0)$ | I _{CBO} | - - | -10 -10 | nAdc μAdc |
| Emitter-Base Cutoff Current (V _{EB} = -4.0 Vdc) (V _{EB} = -5.0 Vdc) | I _{EBO} | - - | -50 -10 | nAdc μAdc |
| ON CHARACTERISTICS (Note 1) | · | | | |
| DC Current Gain $ \begin{array}{l} (I_C = -0.1 \text{ mAdc, } V_{CE} = -10 \text{ Vdc)} \\ (I_C = -1.0 \text{ mAdc, } V_{CE} = -10 \text{ Vdc)} \\ (I_C = -1.0 \text{ mAdc, } V_{CE} = -10 \text{ Vdc)} \\ (I_C = -150 \text{ mAdc, } V_{CE} = -10 \text{ Vdc)} \\ (I_C = -500 \text{ mAdc, } V_{CE} = -10 \text{ Vdc)} \\ \end{array} $ | h _{FE} | 75 100 100 100 50 | - 450 - 300 - | - |
| Collector – Emitter Saturation Voltage ($I_C = -150$ mAdc, $I_B = -15$ mAdc) ($I_C = -500$ mAdc, $I_B = -50$ mAdc) | V _{CE(sat)} | - - | -0.4 -1.6 | Vdc |
| Base – Emitter Saturation Voltage (I _C = -150 mAdc, I _B = -15 mAdc) (I _C = -500 mAdc, I _B = -50 mAdc) | V _{BE(sat)} | -0.6 - | -1.3 -2.6 | Vdc |
| SMALL-SIGNAL CHARACTERISTICS | | I | I | |
| Magnitude of Small–Signal Current Gain (I _C = -20 mAdc, V _{CE} = -20 Vdc, f = 100 MHz) | h _{fe} | 2.0 | _ | _ |
| Small–Signal Current Gain ($I_C = -1.0$ mAdc, $V_{CE} = -10$ Vdc, $f = 1$ kHz) | h _{fe} | 100 | - | - |
| Output Capacitance $(V_{CB} = -10 \text{ Vdc}, I_E = 0, 100 \text{ kHz} \le f \le 1.0 \text{ MHz})$ | C _{obo} | - | 8.0 | pF |
| Input Capacitance $(V_{EB} = -2.0 \text{ Vdc}, I_{C} = 0, 100 \text{ kHz} \le f \le 1.0 \text{ MHz})$ | C _{ibo} | - | 30 | pF |
| SWITCHING CHARACTERISTICS | • | | | • |
| Turn-On Time (Reference Figure in MIL-PRF-19500/291) | t _{on} | - | 45 | ns |
| Turn-Off Time (Reference Figure in MIL-PRF-19500/291) | t _{off} | - | 300 | ns |

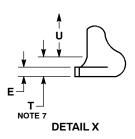
^{1.} Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.

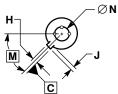
2N2907A

PACKAGE DIMENSIONS

TO-183 CASE 206AA **ISSUE A**









DETAIL

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: INCHES.
- DIMENSION J MEASURED FROM DIAMETER A TO EDGE. LEAD TRUE POSITION TO BE DETERMINED AT THE GUAGE
- PLANE DEFINED BY DIMENSION R.
 DIMENSION F APPLIES BETWEEN DIMENSION P AND L.
- DIMENSION D APPLIES BETWEEN DIMENSION L AND K. BODY CONTOUR OPTIONAL WITHIN ZONE DEFINED BY DIMEN-SIONS A, B, AND T.

| | MILLIMETERS INCHES | | HES | |
|-----|--------------------|-------|-----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 5.31 | 5.84 | 0.209 | 0.230 |
| В | 4.52 | 4.95 | 0.178 | 0.195 |
| С | 4.32 | 5.33 | 0.170 | 0.210 |
| D | 0.41 | 0.53 | 0.016 | 0.021 |
| Е | | 0.76 | | 0.030 |
| F | 0.41 | 0.48 | 0.016 | 0.019 |
| Н | 0.91 | 1.17 | 0.036 | 0.046 |
| J | 0.71 | 1.22 | 0.028 | 0.048 |
| K | 12.70 | 19.05 | 0.500 | 0.750 |
| L | 6.35 | | 0.250 | |
| M | 45°BSC | | 45 °BSC | |
| N | 2.54 BSC | | 0.100 BSC | |
| Р | | 1.27 | | 0.050 |
| R | 1.37 | BSC | 0.054 BSC | |
| Т | | 0.76 | | 0.030 |
| U | 2 54 | | 0.100 | |

STYLE 1:

PIN 1. EMITTER

- BASE
- COLLECTOR

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